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## AMENDMENTS TO THE CLAIMS

The claims have been reproduced in their entirety with appropriate indications of their respective statuses.

 (Currently Amended) A dielectric coating for use on a conductive substrate comprising: a silicone composition silsesquioxane polymer of the formula:

 $[R_xSiO_{(4-x)/2}]_n$ 

wherein x=1-4 and wherein R comprises a compound selected from the group consisting of: methyl, phenyl, hydrido, hydroxyl, alkoxy groups or a combination and combinations of the above, or monovalent radicals independently selected from alkyl, aryl, alkylamide, arylamide, alkylamino groups and or arylamino radicals;

said dielectric coating having a network structure.

2. (Currently Amended) The dielectric coating of claim 1 wherein the silicone composition emprises a silsesquioxane polymer compound of the formula comprises:

[RSiO<sub>3/2</sub>]<sub>n</sub>

wherein R comprises a compound selected from the group consisting of: methyl, phenyl, hydrido, hydroxyl, alkoxy or-a combination and combinations of the above or monovalent radicals independently selected from alkyl, aryl, alkylamide, arylamide, alkylamino groups and or arylamino radicals.

- 3. (Currently Amended) The dielectric coating of claim 2 wherein the silsesquioxane eompound polymer further includes silanol units of the formula: [RSi (OH)<sub>x</sub>O<sub>y</sub>] where x+y=3 and which can be silylated with appropriate organosiloxanes to produce corresponding silylated polysilsesquioxanes.
- (Currently Amended) The dielectric coating of claim 1 wherein the silicone composition silsesquioxane polymer comprises a polymethyl silsesquioxane of the formula: [CH<sub>3</sub>SiO<sub>(3/2)]n</sub>.

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- 5. (Currently Amended) The  $\underline{A}$  dielectric coating of elaim 1 wherein the silicone composition emprises for use on a conductive substrate comprising a silsesquioxane copolymer of the formula:  $R^1 {}_*R^2 {}_bR^3 {}_*SiO_{(4*a+b-c)^2}$ , wherein: a is zero or a positive number, b is zero or a positive number, c is zero or a positive number, with the provisos that  $0.8 \le (a+b+c) \le 3.0$  and wherein the copolymer has an average of at least two  $R^1$  groups per molecule, and each  $R^1$  is a functional group independently selected from the group consisting of hydrogen atoms and monovalent hydrocarbon groups having aliphatic unsaturation, and each  $R^2$  and each  $R^3$  are monovalent hydrocarbon groups independently selected from the group consisting of nonfunctional groups and  $R^1$  said dielectric coating having a network structure.
- 6. (Original) The dielectric coating of claim 5 wherein R<sup>1</sup> is an alkenyl group and R<sup>2</sup> and R<sup>3</sup> are nonfunctional groups selected from the group consisting of alkyl and aryl groups.
- 7. (Original) The dielectric coating of claim 6 wherein R<sup>1</sup> is selected from the group consisting of vinyl and allyl groups.
- 8. (Original) The dielectric coating of claim 6 wherein R<sup>2</sup> and R<sup>3</sup> are selected from the group consisting of methyl, ethyl, isopropyl, n-butyl, and isobutyl groups.
- (Currently Amended) The dielectric coating of claim 1 wherein the silicone composition silsesquioxane polymer comprises a phenyl-methyl siloxane compound of the formula: [(McSiO<sub>3/2</sub>)<sub>0.25</sub>(PhSiO<sub>3/2</sub>)<sub>0.15</sub> (Ph<sub>2</sub>SiO)<sub>0.10</sub>(MePhSiO)<sub>0.50</sub>].
- 10. (Currently Amended) A substrate comprising:
  - a flexible conductive material;
  - a dielectric coating disposed on a surface of the flexible conductive material;
- said dielectric coating comprising a silicone composition silsesquioxane polymer of the formula:  $[R_xSiO_{(t+x)/2}]_n$

wherein x=l-4 and wherein R comprises a compound selected from the group consisting of methyl, phenyl, hydrido, hydroxyl, alkoxy groups or a combination and combinations of the

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above or monovalent radicals independently selected from alkyl, aryl, alkylamide, arylamide, alkylamino groups and or arylamino radicals;

said dielectric coating having a network structure.

11. (Currently Amended) The substrate of claim 10 wherein the silicone composition silsesquioxane polymer comprises a silsesquioxane compound of the formula:

[RSiO<sub>3/2</sub>]<sub>n</sub>

wherein R comprises a compound selected from the group consisting of: methyl, phenyl, hydrido, hydroxyl, alkoxy or a combination and combinations of the above, or monovalent radicals independently selected from alkyl, aryl, alkylamide arylamide, alkylamino groups and or arylamino radicals.

12. (Currently Amended) The substrate of claim 11 wherein the silsesquioxane eompound polymer further includes silanol units of the formula:

[RSi(OH)<sub>v</sub>O<sub>v</sub>]

where x+y=3 and which can be silylated with appropriate organosiloxanes to produce corresponding silylated polysilsesquioxanes.

- 13. (Currently Amended) The substrate of claim 10 wherein the silicone composition silsesquioxane polymer comprises a polymethyl silsesquioxane of the formula: [CH<sub>3</sub>SiO<sub>(3/2)</sub>]<sub>n</sub>.
- 14. (Currently Amended) The A substrate of claim 10 wherein the silicone composition comprises comprising a flexible conductive material, and a dielectric coating disposed on one surface of the flexible conductive material, the dielectric coating comprising a silsesquioxane copolymer of the formula:

 $R^{1}_{a}R^{2}_{b}R^{3}_{c}SiO_{(4-a-b-c)/2}$ 

wherein: a is zero or a positive number, b is zero or a positive number, c is zero or a positive number, with the provisos that  $0.8 \le (a+b+c) \le 3.0$  and wherein the copolymer has an average of at least  $2\ R^1$  groups per molecule, and each  $R^1$  is a functional group independently selected from the group consisting of hydrogen atoms and monovalent hydrocarbon groups

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having aliphatic unsaturation, and each  $R^2$  and each  $R^3$  are monovalent hydrocarbon groups independently selected from the group consisting of nonfunctional groups and  $R^1$ , said dielectric coating having a network structure.

- 15. (Original) The substrate of claim 14 wherein R<sup>1</sup> is an alkenyl group and R<sup>2</sup> and R<sup>3</sup> are nonfunctional groups selected from the group consisting of alkyl and aryl groups.
- 16. (Original) The substrate of claim 15 wherein R<sup>1</sup> is selected from the group consisting of vinyl and allyl groups.
- 17. (Original) The substrate of claim 15 wherein R<sup>2</sup> and R<sup>3</sup> are selected from the group consisting of methyl, ethyl, isopropyl, n-butyl, and isobutyl groups.
- 18. (Currently Amended) The substrate dielectric coating of claim 1 wherein the silicone emposition silsesquioxane polymer comprises a phenyl-methyl siloxane compound of the formula:

- (Currently Amended) The dielectric coating of claim 1, wherein the silicone composition silsesquioxane polymer further comprises a reinforcing filler.
- 20. (Previously Presented) The dielectric coating of claim 19, wherein the reinforcing filler comprises colloidal silica particles having a size of from 5 to 150 nm.
- (Currently Amended) The substrate of claim 10, wherein the silicone composition silsesquioxane polymer further comprises a reinforcing filler.
- 22. (Previously Presented) The substrate of claim 21, wherein the reinforcing filler comprises colloidal silica particles having a size of from 5 to 150 nm.